

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	30	V
Gate-Source Voltage		V _{GSS}	+20 -16	V
Continuous Drain Current (Notes 6 & 9) V _{GS} = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	I _D	25 25	А
Continuous Drain Current (Note 5) V _{GS} = 10V	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	10.4 8.3	А
Maximum Continuous Body Diode Forward Current (Note 5)		I _S	3	А
Pulsed Drain Current (10µs pulse, Duty Cycle = 1%)		I _{DM}	95	А
Avalanche Current, L=0.3mH		I _{AS}	27	Α
Avalanche Energy, L=0.3mH		E _{AS}	110	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T _C = +25°C	P_{D}	42	W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	3	°C/W
Total Power Dissipation (Note 5)	T _A = +25°C	P _D	2.1	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ heta JA}$	60	°C/W
Operating and Storage Temperature Range		$T_{J_1}T_{STG}$	-55 to +150	°C

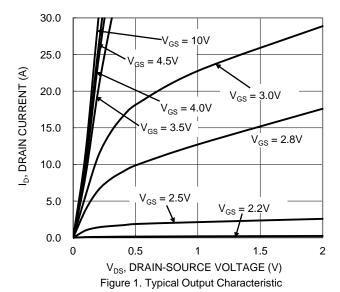
Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1	μΑ	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	100 -100	nA	$V_{GS} = +20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1	-	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		-	3.5	4.5	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	5	7.0		$V_{GS} = 4.5V, I_D = 7A$	
Diode Forward Voltage	V _{SD}	-	0.7	1	V	V _{GS} = 0V, I _S = 1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	-	2370	-	pF	$V_{DS} = 15V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	-	1360	-			
Reverse Transfer Capacitance	C _{rss}	-	240	-			
Gate Resistance	Rg	-	0.6	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qq	-	20	-			
Total Gate Charge (V _{GS} = 10V)	Qq	-	44	-	nC	V _{DS} = 15V, I _D = 20A	
Gate-Source Charge	Q _{gs}	-	7	-	nc		
Gate-Drain Charge	Q _{qd}	-	8	-			
Turn-On Delay Time	t _{D(ON)}	-	6.2	-		$V_{DD} = 15V, V_{GS} = 10V,$ $R_L = 0.75\Omega, R_G = 3\Omega, I_D = 20A$	
Turn-On Rise Time	t _R	-	4.3	-			
Turn-Off Delay Time	t _{D(OFF)}	-	21	-	ns		
Turn-Off Fall Time	t _F	-	8	-			
Body Diode Reverse Recovery Time	t _{RR}	-	25	-	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	-	37	-	nC	$I_F = 15A$, di/dt = 500A/ μ s	

Notes:

- 5. $R_{\theta JA}$ is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. $R_{\theta JC}$ is guaranteed by design O. NouA is determined with the device mounted on FR-4 substrate PC board, 2oz of while RouA is determined by the user's board design.
 6. Thermal resistance from junction to soldering point (on the exposed drain pad).
 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing.
 9. Package limited.





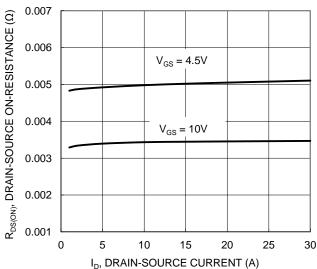


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

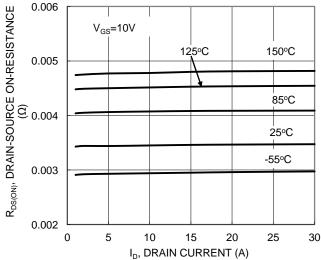


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

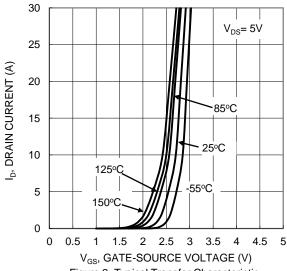


Figure 2. Typical Transfer Characteristic

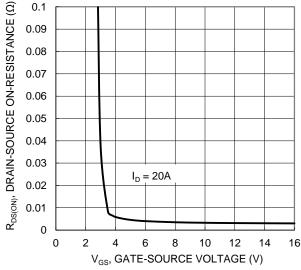


Figure 4. Typical Transfer Characteristic

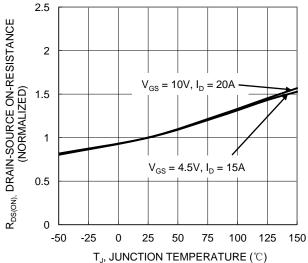


Figure 6. On-Resistance Variation with Junction Temperature



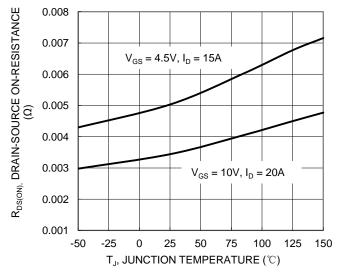
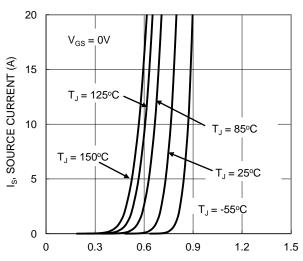


Figure 7. On-Resistance Variation with Junction Temperature



V_{SD}, SOURCE-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current

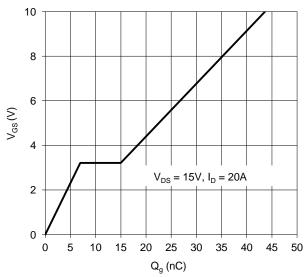


Figure 11. Gate Charge

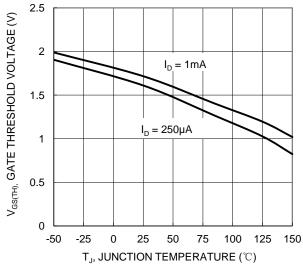
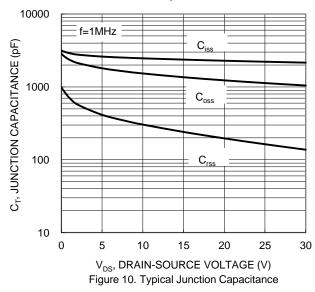


Figure 8. Gate Threshold Variation vs. Junction Temperature



1000 $R_{DS(ON)}$ Limited 100 ID, DRAIN CURRENT (A) 10 =10ms P_W =100ms 1 T_{J(Max)}=150℃ T₄=25°C 0.1 =10s Single Pulse DC DUT on 1*MRP board V_{GS}=10V 0.01 0.01 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



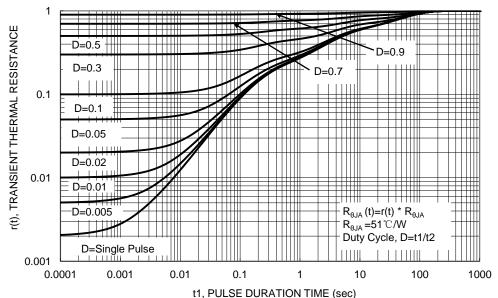


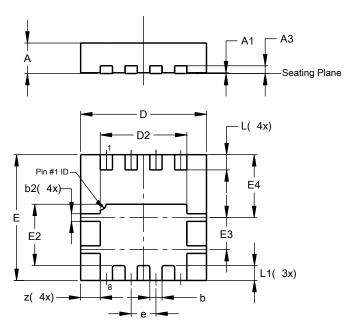
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

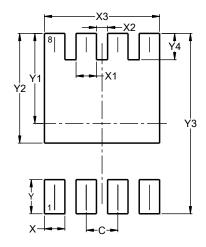


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	_	_	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	-	-	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.370
Υ	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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